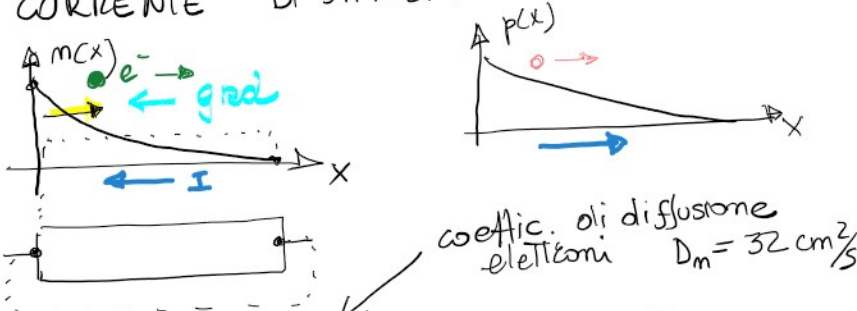


Correnti di diffusione e giunzione pn

martedì 17 marzo 2020 09:30

CORRENTE DI DIFFUSIONE



$$J_{n \text{ diff}} = (-q) D_n [-\text{grad } m(x, y, z)]$$

$$J_{p \text{ diff}} = q D_p [-\text{grad } p(x, y, z)]$$

coeff. di diff. delle lacune $D_p = 12 \text{ cm}^2/\text{s}$

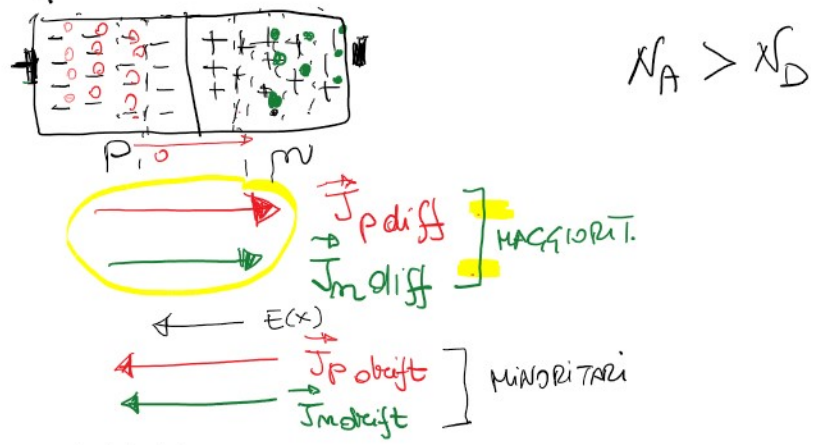
$$J_{\text{tot diff}} = J_{n \text{ diff}} + J_{p \text{ diff}} = (-q) D_n [-\text{grad } m(x, y, z)] + q D_p [-\text{grad } p(x, y, z)]$$

$$D_n = \frac{k_B T}{q} \mu_n$$

$$D_p = \frac{k_B T}{q} \mu_p$$

RELAZ. DI EINSTEIN
 $k_B T \rightarrow$ energia termica
 $V_{th} = \frac{k_B T}{q} \Rightarrow$ tensione termica $\rightarrow 25 \text{ mV}$

GIUNZIONE P-N



EQUILIBRIO

$$|J_{p \text{ diff}}| = |J_{p \text{ drift}}|$$

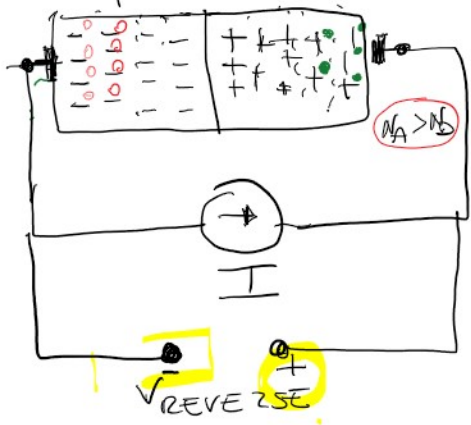
$$|J_{n \text{ diff}}| = |J_{n \text{ drift}}|$$

BILANCIO DETTAGLIATO

TENSIONE DI BUILT IN

TENSIONE DI BUILT IN

POLARIZZAZIONE INVERSA



$$I < I_S$$

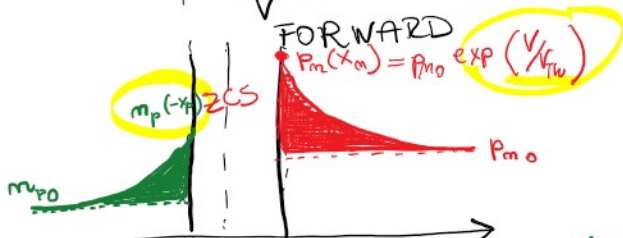
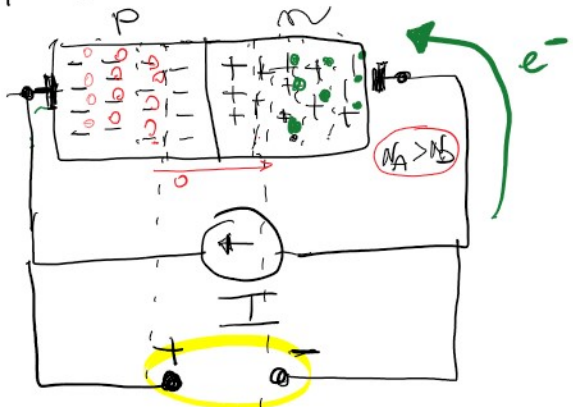
corrente di drift

aumenta la zona di carica spaziale
 ↓
 AUMENTA LA BARRIERA DI POTENZIALE

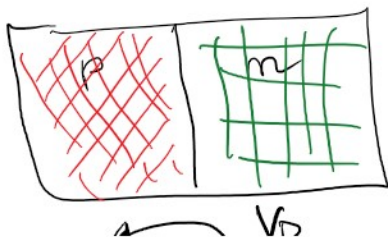
Breakdown della giunzione

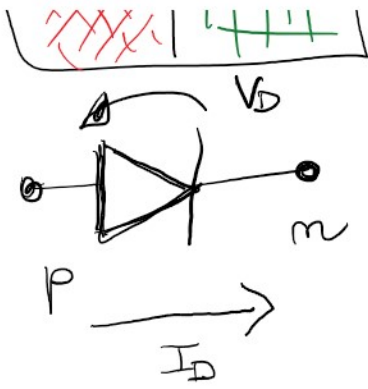
- EFFETTO ZENER $V_{REV} \approx 5V$
- EFFETTO VALANCA $V_{REV} \geq 7V$

GIUNZIONE PN IN POLARIZZAZIONE DIRETTA

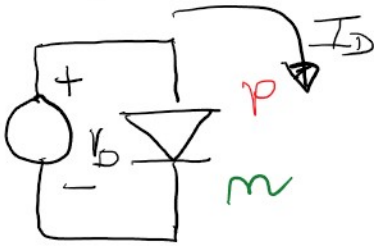


n_{p0} conc. di elettroni minoritari in zona p all'equilib.
 p_{n0} conc. di lacune minoritarie in zona n all'equilib.

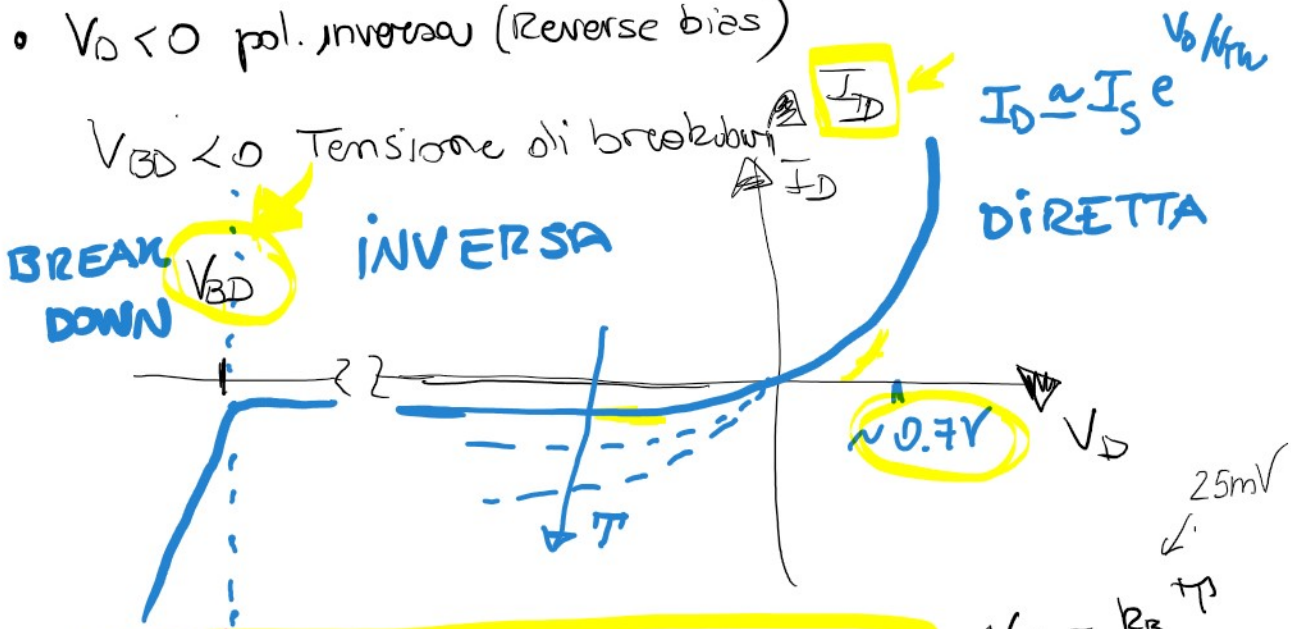




CARATTERISTICA IV DEL DIODO A GIUNZIONE



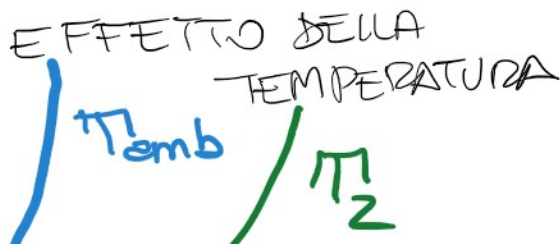
- $V_D > 0$ pol. diretta (Forward bias)
- $V_D < 0$ pol. inversa (Reverse bias)

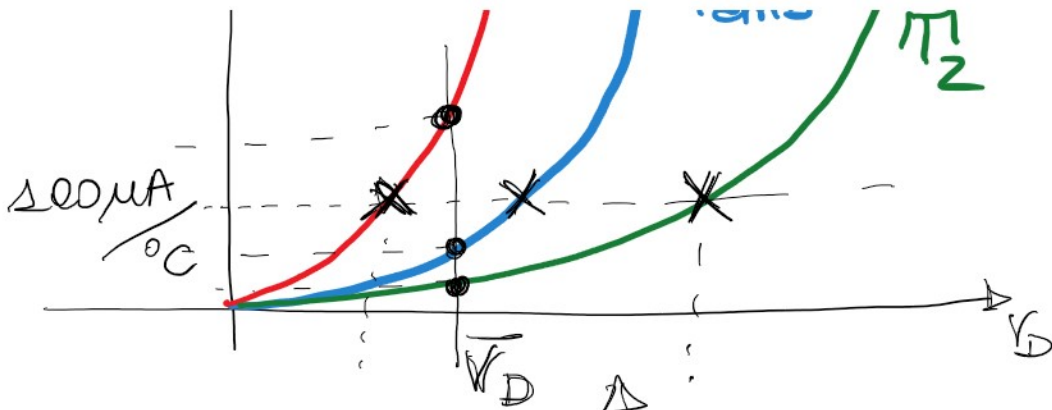


$$I_D = I_S \left[\exp\left(\frac{V_D}{V_{Th}}\right) - 1 \right]$$

I_S : corrente di saturazione inversa

$V_{Th} = \frac{k_B T}{q}$





$\pi_1 > \pi_{amb} > \pi_2$
- 2 ÷ 3 mV/°C

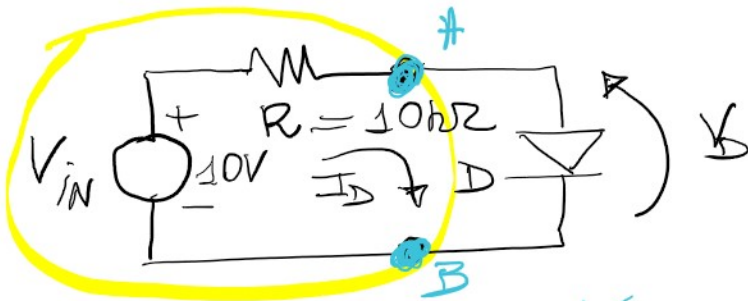
DISSIPAZ. POTENZA

$P \approx 0.7V * I_D$ pol. diretta

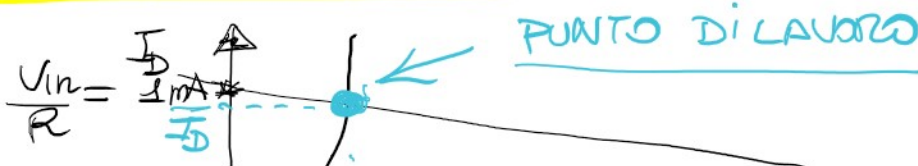
$P \approx 0W$ pol. inversa

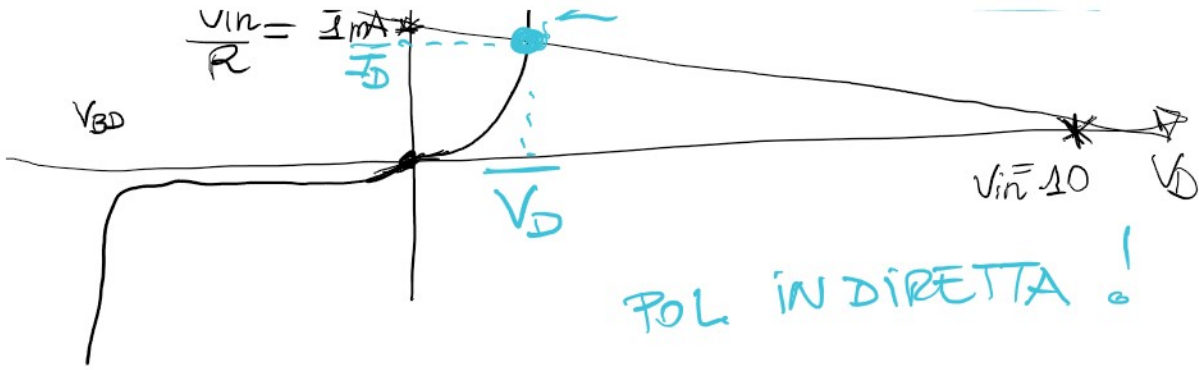
$P \approx |V_{BD}| |I_D|$ Breakdown

ANALISI DI CIRCUITI CON DIODI, MODELLIZZAZIONE DEL DIODO



- * METODO GRAFICO
- * METODO ANALITICO
- * SEMPLIFICAZIONE MEDIANTE MODELLI





$$I_D = I_S \left[\exp\left(\frac{V_D}{V_{Th}}\right) - 1 \right]$$

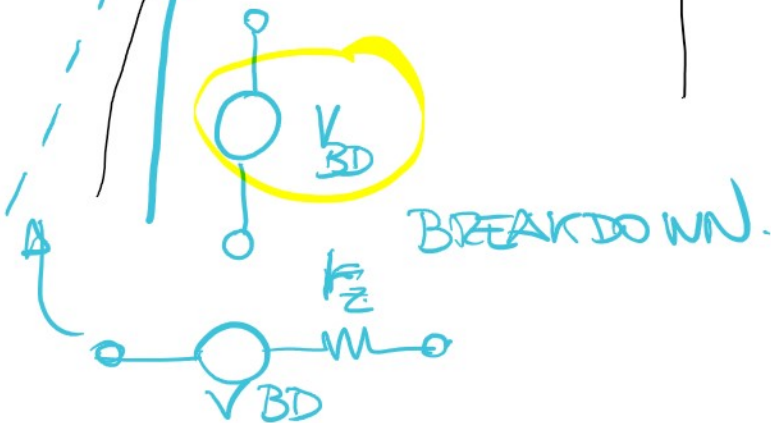
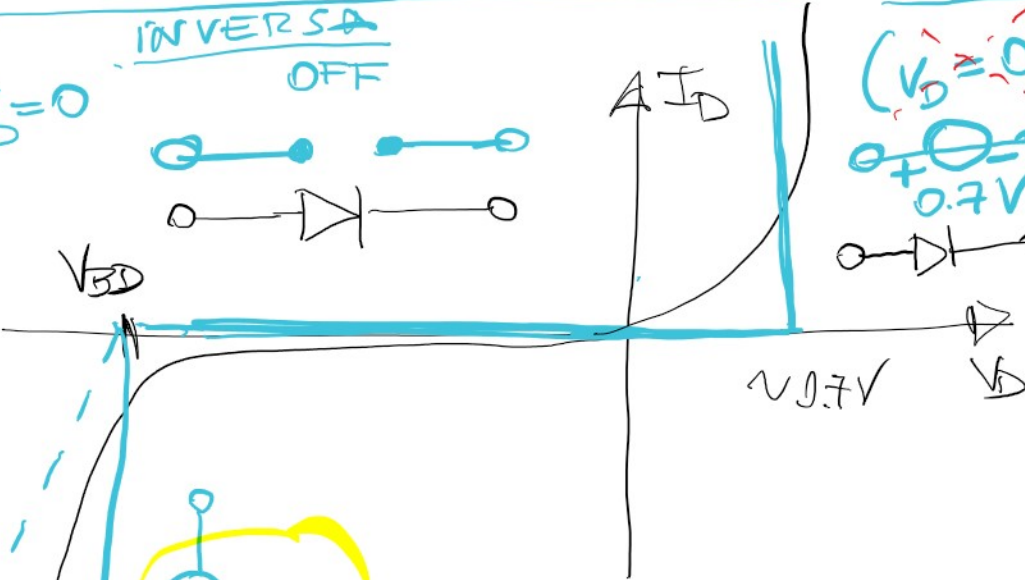
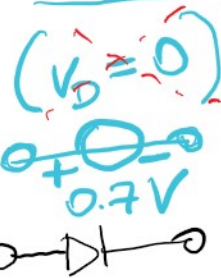
$$V_D = V_{in} - I_D R$$

EQ. TRASCENDENTE

⇒ I_D, V_D ,
DIRETTA:

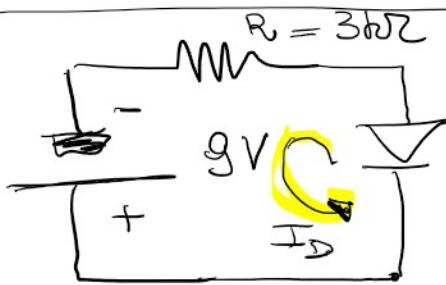
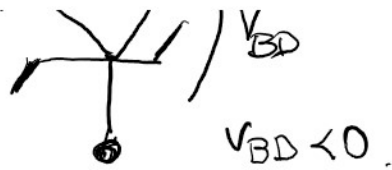
$$V_D = V_{in} - I_S \left[\exp\left(\frac{V_D}{V_{Th}}\right) - 1 \right] R$$

INVERSA
OFF
 $I_D = 0$

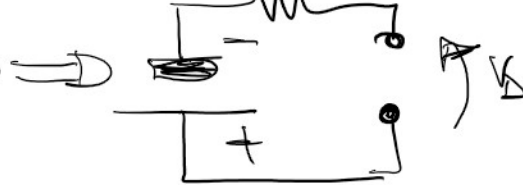


DIODI ZENER



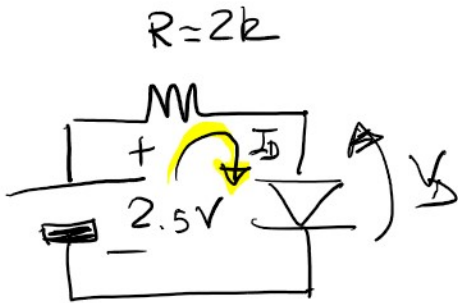


Hp diodo in inversa

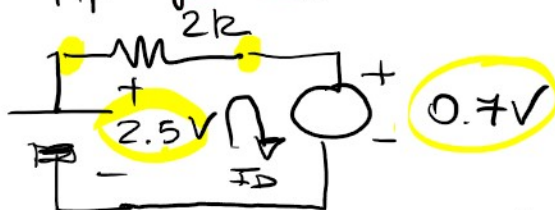


$I_D = 0$

$V_D = -9V$
Ok e in inversa



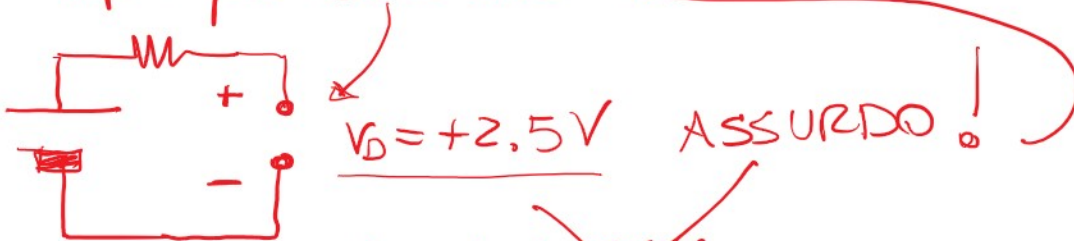
Hp pol. diretta



$I_D > 0$! Ok diodo in diretta

$$I_D = \frac{2.5V - 0.7V}{2k\Omega} = \underline{0.9mA}$$

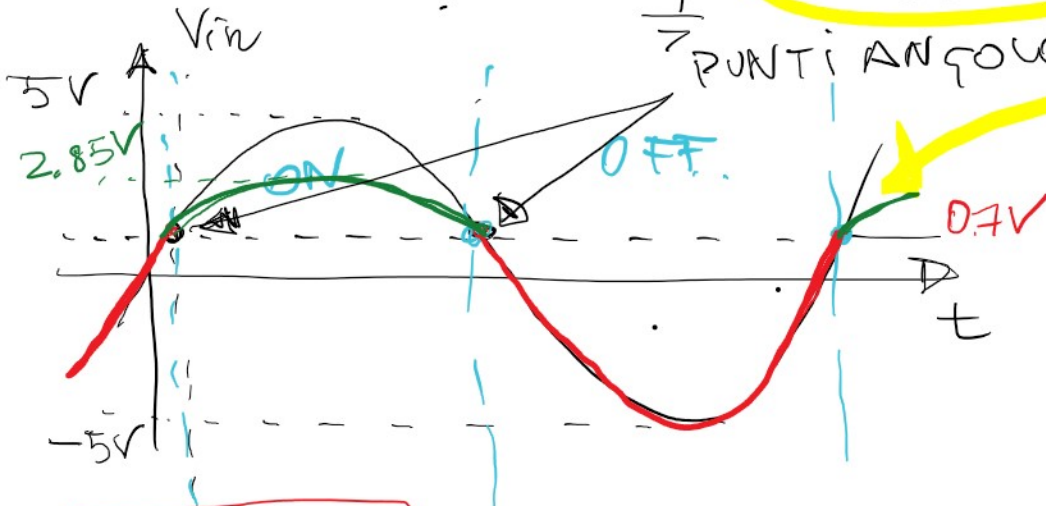
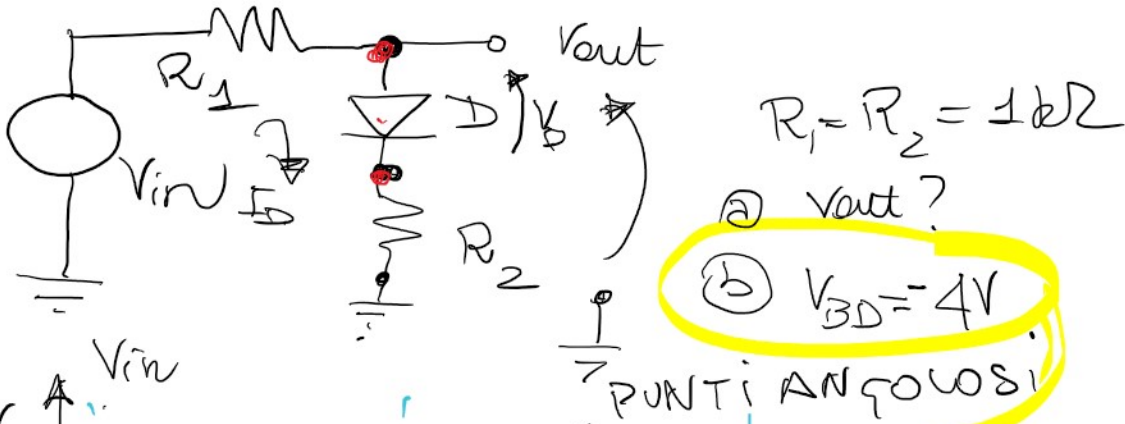
Hp. pol. inversa



~~No } $V_D = 2.5V$
 $I_D = 0$~~

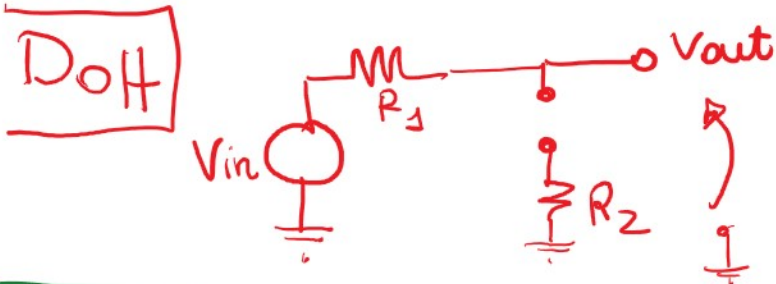
↓ pol. DIRETTA

~~2~~ = 2 ~~4~~ = 4
 POL. DIRETTA



DIODO ON se $V_D \geq 0.7V$
 con diodo off $I_D = 0 \Rightarrow V_{out} = V_D$
 $V_D \geq 0.7V \Leftrightarrow V_{out} \geq 0.7V$
 se diodo off $V_{out} = V_{in} \Rightarrow V_{in} \geq 0.7V$ per avere diodo ON

Don se $V_{in} \geq 0.7V$.

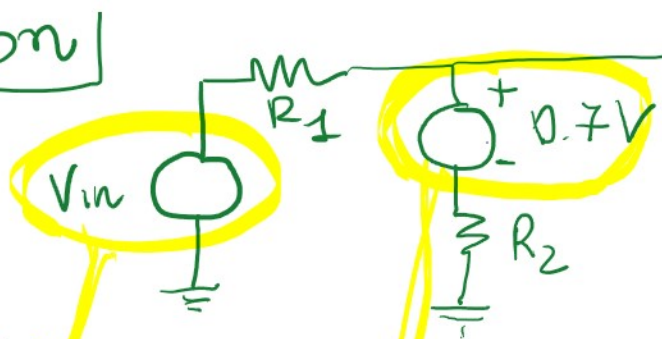


$V_{out} = V_{in}$

Don

$V_{out} = \frac{V_{in}}{2} + 0.35V$

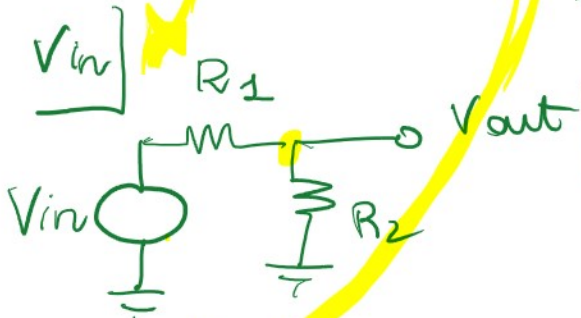
Don



$$V_{out} = \frac{V_{in}}{2} + 0.35V$$

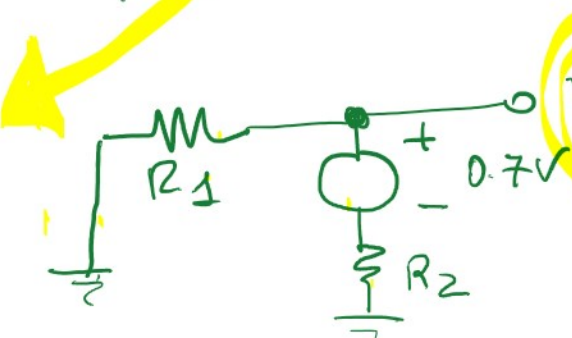
$$V_{out_{max}} = \frac{5}{2} + 0.35V = 2.85V$$

$$V_{out}(V_{in}=0.7V) = \frac{0.7V}{2} + 0.35V = 0.7V$$



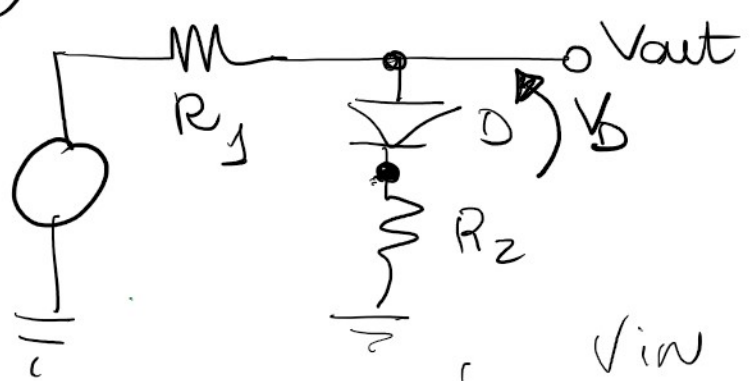
$$V_{in} = \frac{R_2}{R_1 + R_2} V_{in} = \frac{V_{in}}{2}$$

0.7V

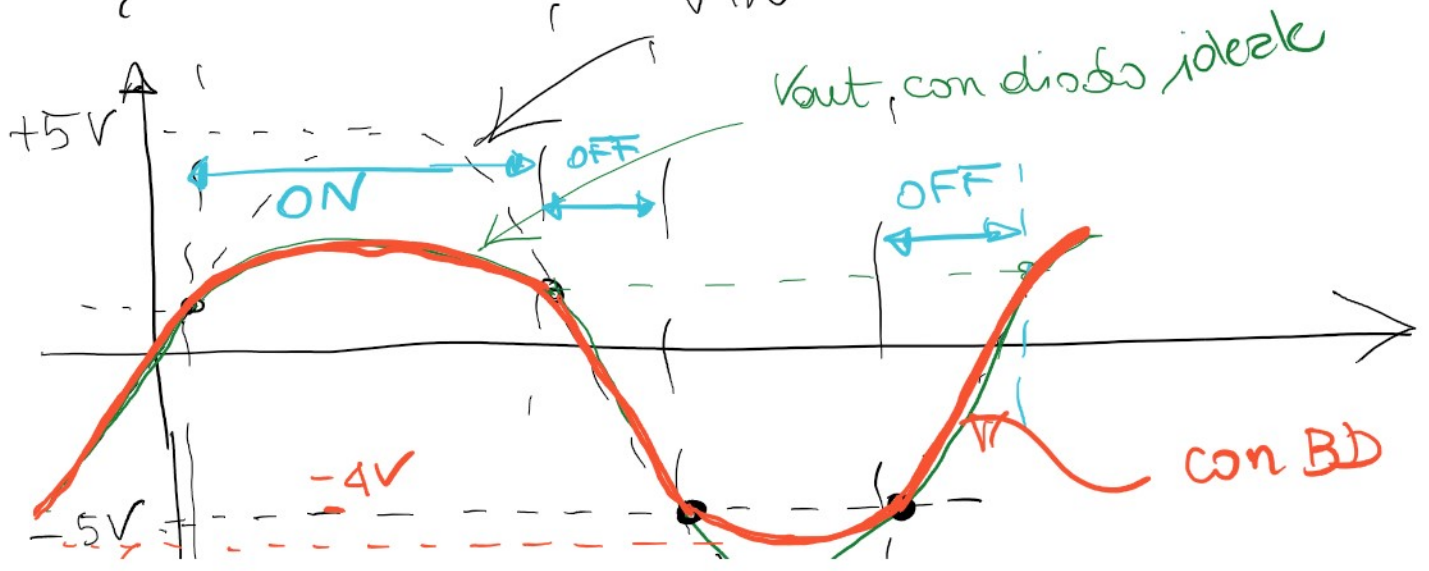


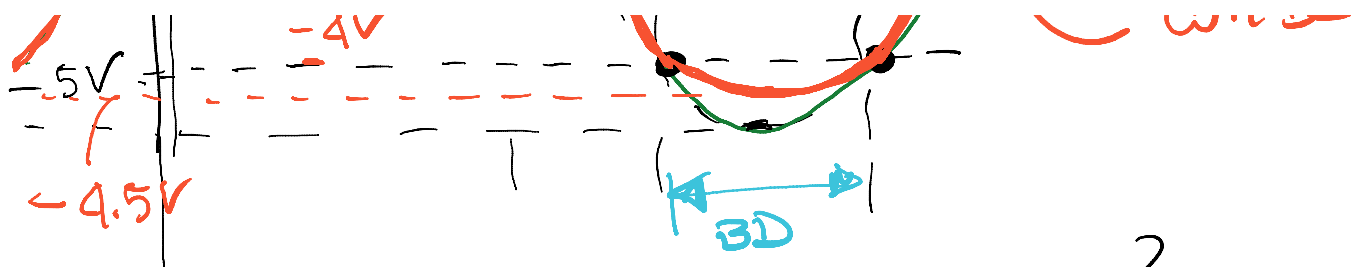
$$V_{out} = 0.7V \frac{R_1}{R_1 + R_2} = 0.35V$$

B)



$$V_{BD} = -4V$$

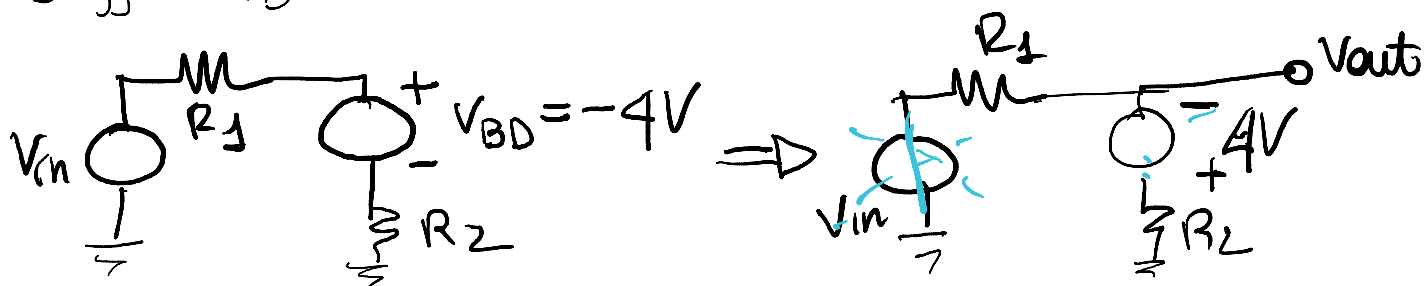




ΔV_{MAX} ai capi del diodo in inversa?

$$V_{D_{MAX}} = -5V \quad !! \quad BD!$$

$$\text{Doff } V_D = -4V \Rightarrow V_{in} = -4V$$



$$V_{out} = \underbrace{\frac{R_2}{R_1 + R_2}}_{V_{in}} V_{in} - \underbrace{4V \frac{R_1}{R_1 + R_2}}_{-4V} =$$

$$= \frac{V_{in}}{2} - \frac{4V}{2} = \frac{V_{in}}{2} - 2V$$

$$V_{in} = -5V \Rightarrow V_{out} = -\frac{5}{2}V - 2V = -4.5V$$

$$V_{in} = -4V \Rightarrow V_{out} = -\frac{4}{2}V - 2V = -4V$$